### **ASDL-4772**

# High Performance Side look AlGaAs/GaAs Infrared (940nm) Lamp



## **Data Sheet**

#### Description

ASDL-4772 is a high performance Infrared emitter that is optimized for high efficiency at emission wavelength of 940nm. It is designed for applications that require small outline dimensions with high radiant intensity and low forward voltage at wide viewing angle. The emitter is encapsulated in Side Look package and is matched to ASDL-6771 for maximum sensitivity.

#### **Features**

- Side Look Package
- 940nm wavelength
- Narrow Viewing Angle
- Good Mechanical and Spectral matching to ASDL-6771 Infrared Phototransistor Detector
- Lead Free and ROHS Compliant
- Available in Tape & Reel

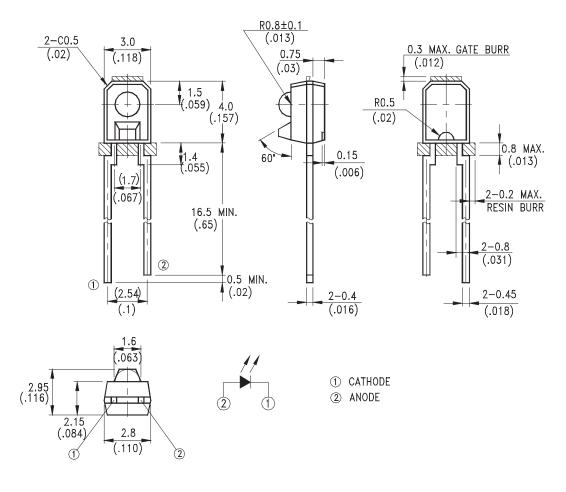
#### **Applications**

- Industrial Infrared Monitoring Applications
- Consumer Electronics (Optical Mouse)
- Infrared Source for Optical Counters and Card Readers
- Photo-Interrupters
- On-Off Switch / Beam Interruption
- Positioning Sensing

### **Ordering Information**

Part Number	Lead Form	Color	Packaging	Shipping Option
ASDL-4772-C22 ASDL-4772-C41	Straight	Clear	Tape & Reel Bulk	4000pcs 20Kpcs / Carton

#### **Package Dimensions**



#### Notes

- 1. All dimensions are in millimeters (inches)
- 2. Tolerance is + 0.25mm (.010") unless otherwise noted
- 3. Protruded resin under flange is 1.0mm (.039") max
- 4. Lead spacing is measured where leads emerge from package
- 5. Specifications are subject to change without notice

## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Min.	Max	Unit	Reference	
Peak Forward Current	I <sub>FPK</sub>		1	А	300pps	
Continuous Forward Current	I <sub>FDC</sub>		50	mA		
Power Dissipation	P <sub>DISS</sub>		75	mW		
Reverse Voltage	$V_{R}$		5	V		
Operating Temperature	T <sub>0</sub>	-40	85	°C		
Storage Temperature	Ts	-55	100	°C		
LED Junction Temperature	Tj		110	°C		
Lead Soldering Temperature	260 °C for 5 sec					

## **Electrical Characteristics at 25°C**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	$V_{F}$		1.2	1.6	V	I <sub>FDC</sub> =20mA
Reverse Voltage	$V_{R}$	5			V	$I_R = 100uA$
Thermal Resistance, Junction to Ambient	$R\Theta_{JA}$		350		°C/W	

# Optical Characteristics at 25°C

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Radiant Intensity	I <sub>E</sub>	1.203		2.707	mW/Sr	I <sub>FDC</sub> =20mA
Viewing Angle	2θ <sub>1/2</sub>		30		deg	
Peak wavelength	λρК		940		nm	I <sub>FDC</sub> = 20mA
Spectral Width	Δλ		50		nm	I <sub>FDC</sub> = 20mA
Optical Rise Time	t <sub>r</sub>		1		us	I <sub>FPK</sub> =100mA Duty Factor=50% Pulse Width=10us
Optical Fall Time	t <sub>f</sub>		1		us	I <sub>FPK</sub> =100mA Duty Factor=50% Pulse Width=10us

### Typical Electrical/Optical Characteristics Curves (T<sub>A</sub>=25°C unless otherwise indicated)

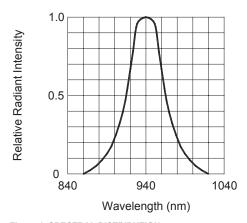


Figure 1. SPECTRAL DISTRIBUTION

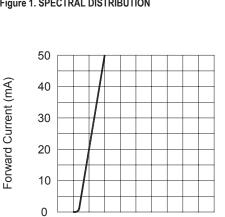


Figure 3. FORWARD CURRENT VS. FORWARD VOLTAGE

1.6

Forward Voltage (V)

2.0

2.4

2.8

1.2

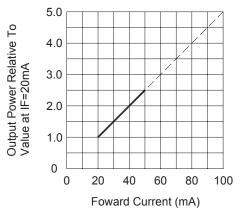


Figure 5. RELATIVE RADIANT INTENSITY VS. FORWARD CURRENT

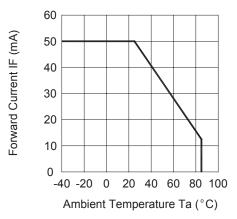


Figure 2. FORWARD CURRENT VS. AMBIENT TEMPERATURE

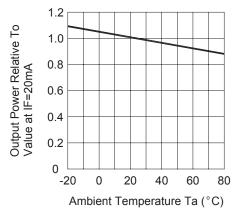


Figure 4. RELATIVE RADIANT INTENSITY VS. AMBIENT TEMPERATURE

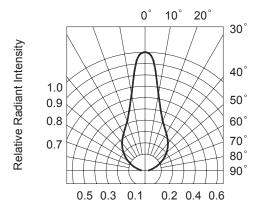


Figure 6. RADIATION DIAGRAM

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

